



SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

ECH8402 — General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	±20	V
Drain Current (DC)	١D	03.70.2	10	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cy <mark>cle≤1%</mark>	40	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	1.6	W
Channel Temperature	Tch	Man	150	°C
Storage Temperature	Tstg	6.00	-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0		3.7	1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0		and We	±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.0		2.4	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =5A	5.6	9.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=5A, VGS=10V		11	15	mΩ
	R _{DS} (on)2	ID=2.5A, VGS=4V		23	32	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		1400		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		270		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		190		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		17		ns
Rise Time	tr	See specified Test Circuit.		82		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		96	STATUS	ns
Fall Time	tf	See specified Test Circuit.		53	11/20	ns

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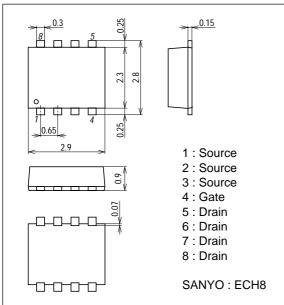
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =5A		28		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =5A		4.8		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =5A		7.3		nC
Diode Forward Voltage	V _{SD}	IS=10A, VGS=0		0.81	1.2	V

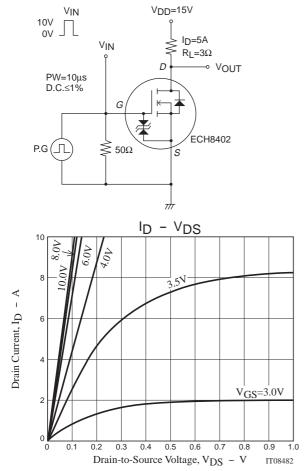
Package Dimensions

unit : mm

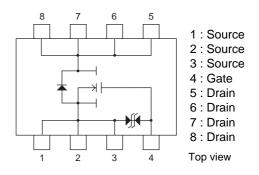
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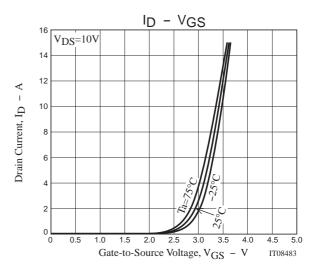


Switching Time Test Circuit

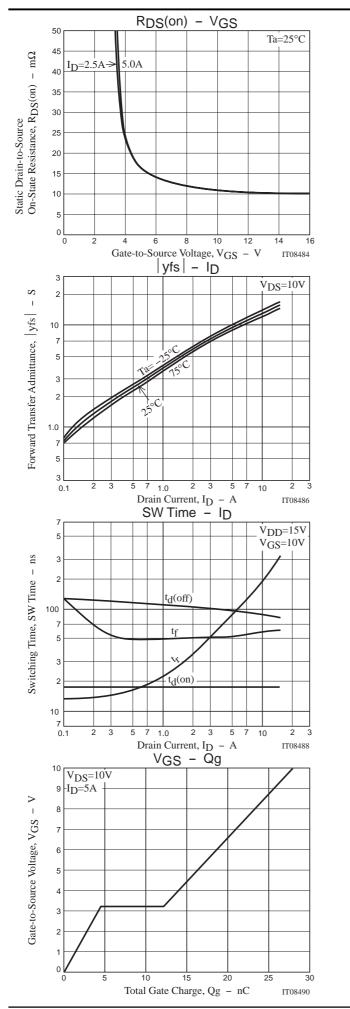


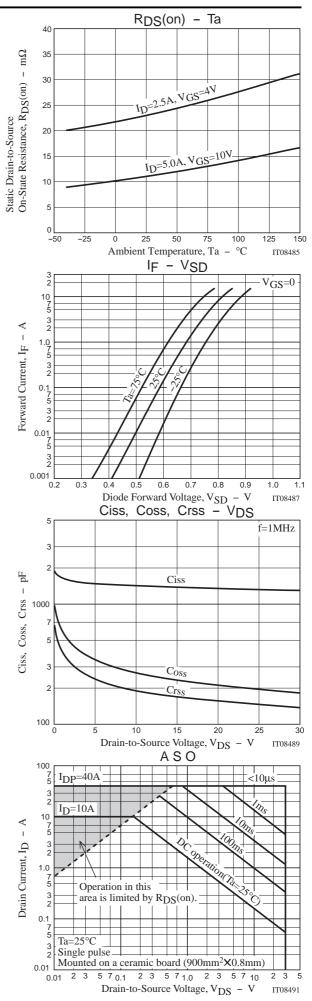
Electrical Connection



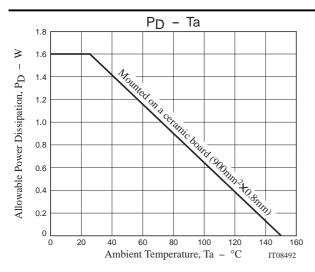


ECH8402





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Note on usage : Since the ECH8402 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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